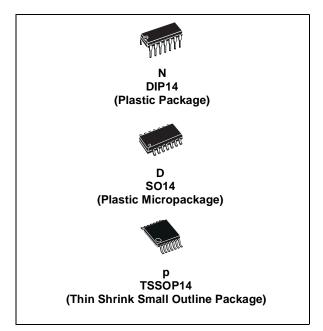


TL084 TL084A - TL084B

GENERAL PURPOSE J-FET QUAD OPERATIONAL AMPLIFIERS

- WIDE COMMON-MODE (UP TO V_{CC}⁺) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT **STAGE**
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE: 16V/µs (typ)



DESCRIPTION

The TL084, TL084A and TL084B are high speed J-FET input guad operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

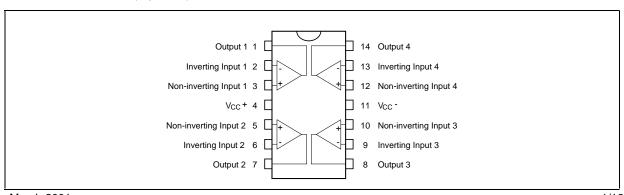
The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

ORDER CODE

Part Number	Temperature Package			
r art ivaniber	Range	N	D	Р
TL084M/AM/BM	-55°C, +125°C	•	•	•
TL084I/AI/BI	-40°C, +105°C	•	•	•
TL084C/AC/BC	0°C, +70°C	•	•	•
Example: TI 0840	CN. TI 084CD			

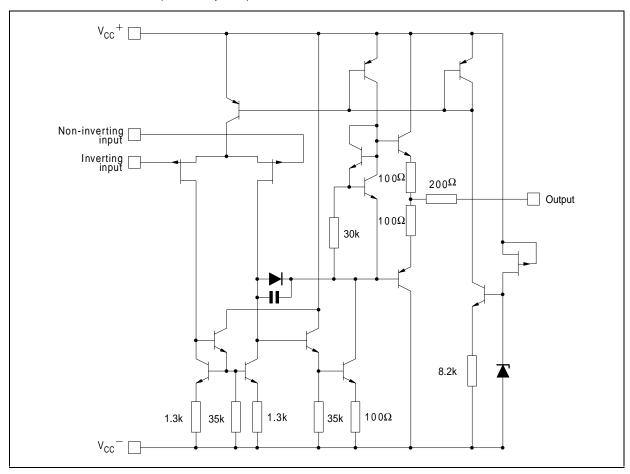
N = Dual in Line Package (DIP)
 D = Small Outline Package (SO) - also available in Tape & Reel (DT)
 P = Thin Shrink Small Outline Package (TSSOP) - only available in Tape & Reel (PT)

PIN CONNECTIONS (top view)



March 2001 1/12

SCHEMATIC DIAGRAM (each amplifier)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TL084M, AM, BM	TL084I, AI, BI	TL084C, AC, BC	Unit	
V _{CC}	Supply voltage - note 1) ±18				٧	
V _i	Input Voltage - note ²⁾	±15				
V _{id}	Differential Input Voltage - note 3)	±30				
P _{tot}	Power Dissipation	680				
	Output Short-circuit Duration - note 4)	Infinite				
T _{oper}	Operating Free-air Temperature Range	-55 to +125 -40 to +105 0 to +70		°C		
T _{stg}	Storage Temperature Range	-65 to +150				

- All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}.
- 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

ELECTRICAL CHARACTERISTICS

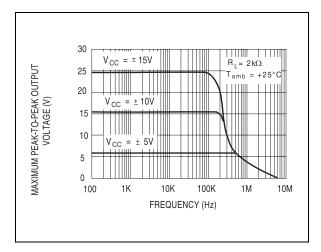
 $V_{CC} = \pm 15V$, $T_{amb} = +25$ °C (unless otherwise specified)

Symbol	Parameter		TL084I,M,AC,AI,AM, BC,BI,BM			TL084C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
V _{io}	Input Offset Voltage (R_s = 50 Ω) T_{amb} = +25°C		3 3 1	10 6 3 13 7 5		3	10	mV
DV _{io}	Input Offset Voltage Drift		10			10		μV/°C
I _{io}	Input Offset Current - note ¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 4		5	100 4	pA nA
I _{ib}	Input Bias Current -note 1 $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20		20	400 20	pA nA
A _{vd}	Large Signal Voltage Gain $(R_L = 2k\Omega, V_0 = \pm 10V)$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I _{CC}	Supply Current, no load, per amplifier $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V _{icm}	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
l _{os}	Output Short-circuit Current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	10 10	40	60 60	10 10	40	60 60	mA
±V _{opp}	$\begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = +25^{\circ}\text{C} & \text{RL} = 2k\Omega \\ & \text{RL} = 10k\Omega \\ T_{min} \leq T_{amb} \leq T_{max} & \text{RL} = 2k\Omega \\ & \text{RL} = 10k\Omega \end{array}$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate ($T_{amb} = +25^{\circ}C$) $V_{in} = 10V$, $R_{L} = 2k\Omega$, $C_{L} = 100pF$, unity gain	8	16		8	16		V/µs
t _r	Rise Time ($T_{amb} = +25^{\circ}C$) $V_{in} = 20$ mV, $R_L = 2$ k Ω , $C_L = 100$ pF, unity gain		0.1			0.1		μs
K _{ov}	Overshoot ($T_{amb} = +25^{\circ}C$) $V_{in} = 20$ mV, $R_L = 2$ k Ω , $C_L = 100$ pF, unity gain		10			10		%
GBP	Gain Bandwidth Product (T_{amb} = +25°C) V_{in} = 10mV, R_L = 2k Ω , C_L = 100pF, f= 100kHz	2.5	4		2.5	4		MHz
R _i	Input Resistance		10 ¹²			10 ¹²		Ω

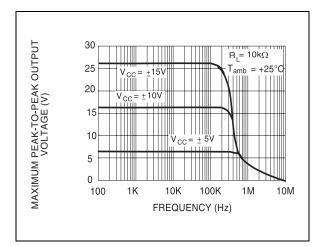
Symbol	Parameter	TL084I,M,AC,AI,AM, BC,BI,BM			TL084C			Unit
			Тур.	Max.	Min.	Тур.	Max.	
THD	Total Harmonic Distortion (T_{amb} = +25°C), f= 1kHz, R_L = 2k Ω , C_L = 100pF, A_v = 20dB, V_o = 2 V_{pp}		0.01			0.01		%
e _n	Equivalent Input Noise Voltage $R_S = 100\Omega$, $f = 1KHz$		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
Øm	Phase Margin		45			45		degrees
V ₀₁ /V ₀₂	Channel Separation $A_v = 100$		120			120		dB

^{1.} The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

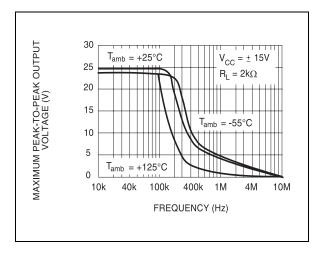
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



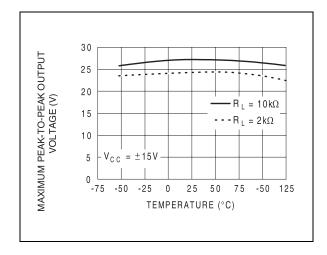
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



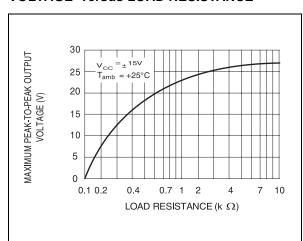
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



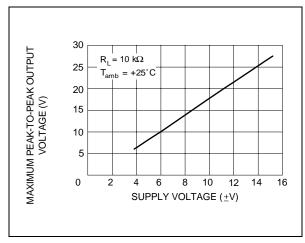
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.



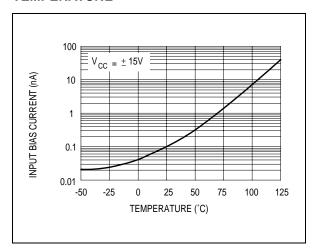
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE



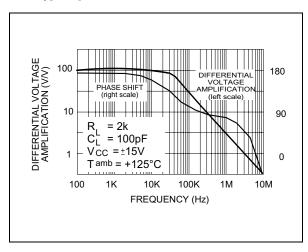
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE



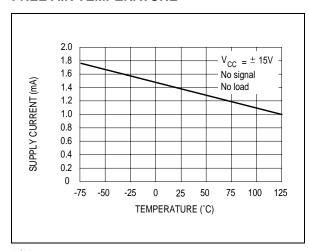
INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



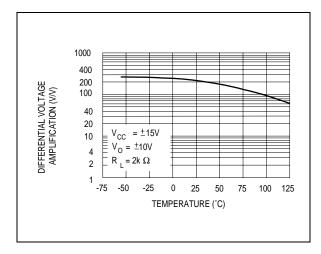
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



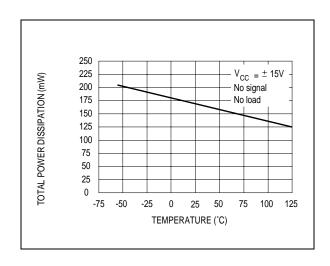
SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



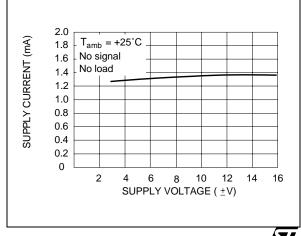
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.



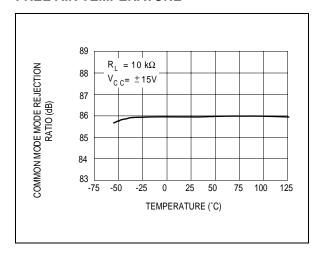
TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



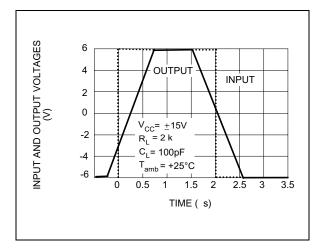
SUPPLY CURRENT PER AMPLIFIER versus SUPPLY VOLTAGE



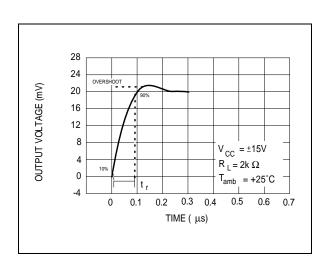
COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



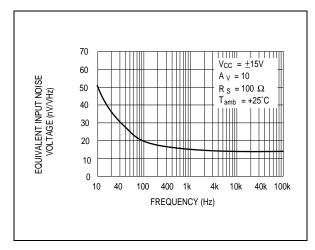
VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



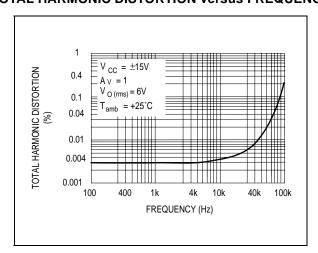
OUTPUT VOLTAGE versus ELAPSED TIME



EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY



TOTAL HARMONIC DISTORTION versus FREQUENCY



PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

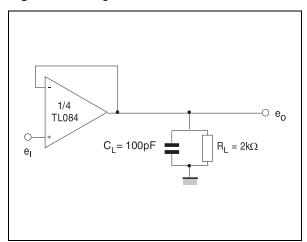
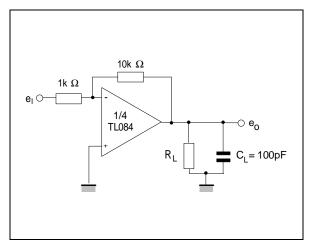
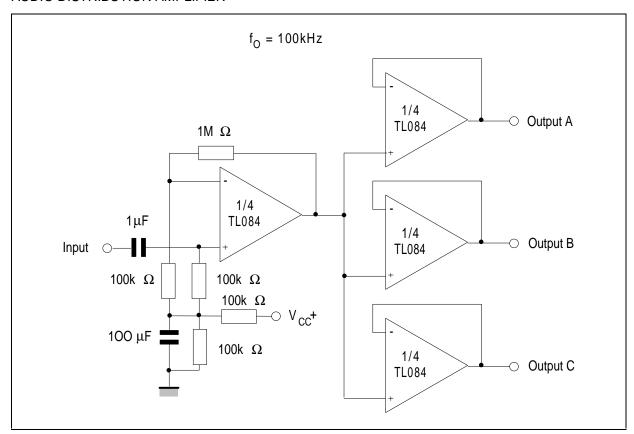


Figure 2 : Gain-of-10 Inverting Amplifier



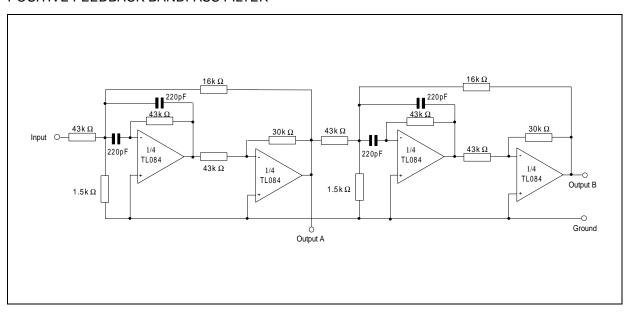
TYPICAL APPLICATIONS

AUDIO DISTRIBUTION AMPLIFIER

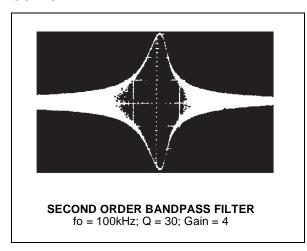


TYPICAL APPLICATIONS (continued)

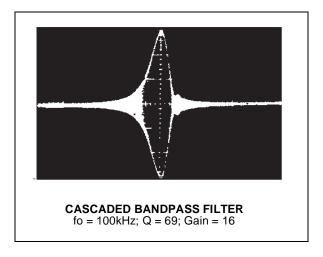
POSITIVE FEEDBACK BANDPASS FILTER



OUTPUT A

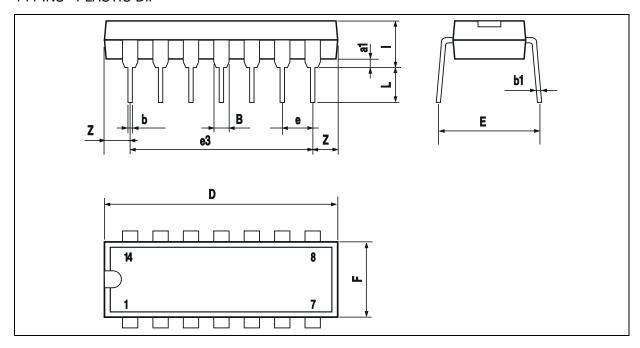


OUTPUT B



PACKAGE MECHANICAL DATA

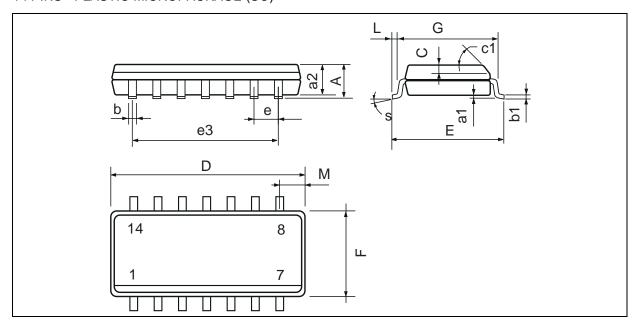
14 PINS - PLASTIC DIP



Dim		Millimeters				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.51			0.020		
В	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



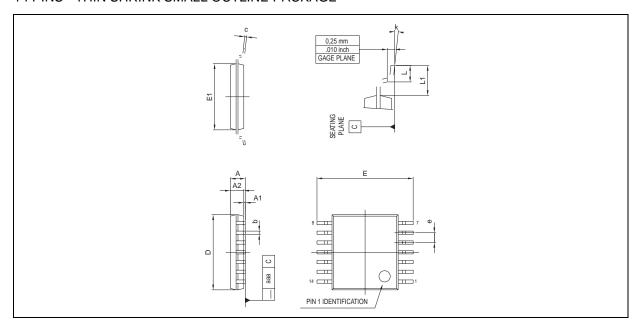
Dim.	Millimeters			Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.			
Α			1.75			0.069			
a1	0.1		0.2	0.004		0.008			
a2			1.6			0.063			
b	0.35		0.46	0.014		0.018			
b1	0.19		0.25	0.007		0.010			
С		0.5			0.020				
c1			45°	(typ.)					
D (1)	8.55		8.75	0.336		0.344			
Е	5.8		6.2	0.228		0.244			
е		1.27			0.050				
e3		7.62			0.300				
F (1)	3.8		4.0	0.150		0.157			
G	4.6		5.3	0.181		0.208			
L	0.5		1.27	0.020		0.050			
М			0.68			0.027			
S		8° (max.)							

Note: (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

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PACKAGE MECHANICAL DATA

14 PINS - THIN SHRINK SMALL OUTLINE PACKAGE



Dim	Millimeters			Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.20			0.05	
A1	0.05		0.15	0.01		0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.15	
С	0.09		0.20	0.003		0.012	
D	4.90	5.00	5.10	0.192	0.196	0.20	
E		6.40			0.252		
E1	4.30	4.40	4.50	0.169	0.173	0.177	
е		0.65			0.025		
k	0°		8°	0°		8°	
I	0.50	0.60	0.75	0.09	0.0236	0.030	

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